

### CDMA LOW NOISE AMPLIFIER/MIXER 900MHz DOWNCONVERTER

### **Typical Applications**

- CDMA/JCDMA Cellular Systems
- CDMA450 Handsets/Data Cards
- AMPS Cellular Systems

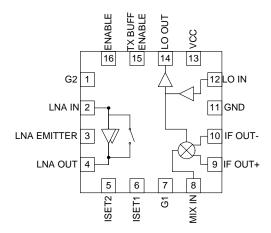
- General Purpose LNA and Downconverter
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment

### **Product Description**

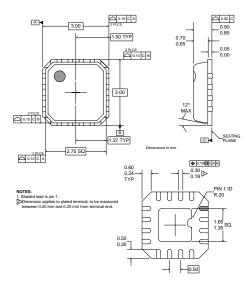
The RF2861 is a receiver front-end for CDMA cellular applications, including JCDMA and CDMA450. It is designed to amplify and downconvert RF signals, using a three gain state LNA to obtain 17dB of stepped gain control. Features include digital control of LNA gain and power down mode, along with an integrated TX LO buffer amplifier. Another feature of the chip is adjustable IIP3 of the LNA and mixer using off-chip current setting resistors to allow for minimum DC current consumption. Noise figure, IIP3, and other specs are designed to be compatible with the TIA/EIA 98D standard for CDMA cellular communications. The IC is manufactured on an advanced Silicon Germanium Bi-CMOS process and is in a 3mmx3mm, 16-pin, QFN.

### **Optimum Technology Matching® Applied**

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**Functional Block Diagram** 



Package Style: QFN, 16-Pin, 3x3

### **Features**

- 3mmx3mm LNA/Mixer Solution
- Adjustable LNA and Mixer Current/IIP3
- Meets IMD Tests with Three Gain States/Two Logic Control Pins
- Integrated TX LO Buffer Amplifier
- Full ESD Protection on all Pins

#### Ordering Information

RF2861 CDMA Low Noise Amplifier/Mixer 900 MHz Downconverter

RF2861 PCBA-410 Fully Assembled Evaluation Board

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### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	-0.5 to +5.0	$V_{DC}$
Input LO and RF Levels	+6	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



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Doromotor	Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition
Overall					T=25°C, V <sub>CC</sub> =2.75V
RF Frequency Range		460 to 900		MHz	
IF Frequency Range	0.1		400	MHz	
Power Supply					
Supply Voltage	2.65	2.75	3.15	V	
Logic High	1.8			V	
Logic Low			0.4	V	
Cellular CDMA Band	•				Freq=869MHz to 894MHz
JCDMA Band					Freq=832MHz to 870MHz
LNA (High Gain)					LNA 50Ω match
Gain	13.0	14.5	16.0	dB	
Noise Figure		1.1	1.3	dB	
Input IP3	9.0	11.0		dBm	
Current		7.0		mA	
Isolation	18.5			dB	
LNA (Mid Gain)					
Gain	4.0	6.0	7.0	dB	
Noise Figure		3.0	3.3	dB	
Input IP3	7.0	9.0		dBm	
Current		3.5		mA	
Isolation	12.5			dB	
LNA (Low Gain)					
Gain	-4.0	-2.5	-1.0	dB	
Noise Figure		2.5	4.0	dB	
Input IP3	+25.0	+27.0		dBm	
Current		0		mA	
Isolation	1.0			dB	
Mixer - CDMA/JCDMA/FM					IF tune set for nominal mixer gain, high IIP3
Gain	9.0	10.5	12.0	dB	
Noise Figure		7.5	8.0	dB	184MHz IF (NF=8.3dB, 85MHz IF)
Input IP3	+6.0	+8.5		dBm	
LO to RF Isolation	36			dB	LO=1064MHz
Mixer - CDMA/JCDMA/FM					IF tune set for high mixer gain, nominal IIP3
Gain		13.0		dB	
Noise Figure		7.5		dB	184MHz IF (NF=8.3dB, 85MHz IF)
Input IP3		+6.5		dBm	
LO to RF Isolation	36			dB	LO=1064MHz
Cascade - High Gain					
Current		25	30	mA	TX LO Buffer Off

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Doromotor		Specificatio	n	Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Cellular CDMA Band		•				
JCDMA Band, cont'd						
Other						
LO-IF Isolation	30			dB	LO=1064MHz	
RF-IF Isolation	45			dB		
LNA Out to Mixer In Isolation	45			dB		
LO-LNA In Isolation, Any State	40			dB	LO=1064MHz	
Control Lines						
Input Capacitance			1	pF	G1, G2, ENABLE, TX BUFF ENABLE	
Local Oscillator Input						
Cellular - CDMA or FM						
Input Power	-10	-4	0	dBm		
Input Frequency	685		710	MHz	IF=184MHz	
	1053		1078	MHz	IF=184MHz	
	784		809	MHz	IF=85MHz	
	954		979	MHz	IF=85MHz	
Cellular - JCDMA						
Input Power	-10	-4	0	dBm		
Input Frequency	722		760	MHz	IF=110MHz	
	942		980	MHz	IF=110MHz	
CDMA450						
Input Power	-10	-4	0	dBm		
Input Frequency	505		575	MHz	IF=85MHz	
CDMA450 Band					Freq=463MHz to 467MHz	
LNA (High Gain)					LNA 50Ω match	
Gain		15.0		dB		
Noise Figure		1.4		dB		
Input IP3		+8.0		dBm		
Current		8.7		mA		
Isolation	18.5			dB		
LNA (Mid Gain)						
Gain		+2.5		dB		
Noise Figure		2.9		dB		
Input IP3		+14.0		dBm		
Current		4.7		mA		
Isolation	12.5			dB		
LNA (Low Gain)						
Gain		-4.0		dB		
Noise Figure		4.0		dB		
Input IP3		+25.0		dBm		
Current		0		mA		
Isolation	1.0			dB		
Mixer					IF tune set for high mixer gain, nominal IIP3	
Gain		12.0		dB	_	
Noise Figure		7.5		dB		
Input IP3		5.0		dBm		
LO to RF Isolation	36			dB	LO=549MHz	
CDMA450 Isolation						
LO-IF Isolation	25			dB	LO=549MHz	
RF-IF Isolation	40			dB		
LNA Out to Mixer In Isolation	40			dB		
LO-LNA In Isolation, Any State	30			dB	LO=549MHz	

Parameter		Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Offic	Condition	
TX (Local Oscillator)						
Buffer Output						
Cellular - CDMA or FM						
Output Power	-7	-5	-3	dBm	Single-ended $50\Omega$ load	
Output Frequency	685		710	MHz	IF=184MHz	
	1053		1078	MHz	IF=184MHz	
	784		809	MHz	IF=85MHz	
	954		979	MHz	IF=85MHz	
Current Consumption		2		mA		
Cellular - JCDMA						
Output Power	-7	-5	-3	dBm	Single-ended $50\Omega$ load	
Output Frequency	722		760	MHz	IF=110MHz	
	942		980	MHz	IF=110MHz	
Current Consumption		2		mA		
CDMA450						
Output Power	-7	-5	-3	dBm	Single-ended $50\Omega$ load	
Output Frequency	505		575	MHz	IF=85MHz	
Current Consumption		2		mA		

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**Gain Control Logic Table** 

Gain State	ENABLE	G1	G2
High Gain	1	0	0
Mid Gain	1	1	0
Low Gain	1	1	1
Low Gain (alternate)	1	0	1

NOTES: All IDC current numbers include bias circuitry current of 1.5mA to 2.0mA (dependent on mode). TX Buffer On: Add 2mA to total current.

### Cell Band Cascaded Performance High Mixer Gain Nominal IIP3 (Typical Values for V<sub>CC</sub>=2.75V)

NOTE: All total current numbers include bias circuitry current of 1.5mA to 2.0mA (dependent on mode).

Parameter	CELL CDMA				
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)		
Cascaded:					
Gain (dB)	25.0	16.5	8.0		
Noise Figure (dB)	2.1	6.3	12.5		
Input IP3 (dBm)	-5.6	+2.0	+11.4		
Total Current (mA)	25.0	21.5	18.0		

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

### Cell Band Cascaded Performance Nominal Mixer Gain High IIP3 (Typical Values for $V_{CC}$ =2.75V)

Parameter	CELL CDMA				
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)		
Cascaded:					
Gain (dB)	22.5	14.0	5.5		
Noise Figure (dB)	2.1	6.3	12.5		
Input IP3 (dBm)	-3.7	+3.5	+13.3		
Total Current (mA)	25.0	21.5	18.0		

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

### CDMA450 Band Cascaded Performance (Typical Values for V<sub>CC</sub>=2.75V)

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Parameter	CDMA450			
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)	
Cascaded:				
Gain (dB)	24.5	12.0	5.5	
Noise Figure (dB)	2.2	8.5	14.0	
Input IP3 (dBm)	-7.6	+4.5	+11.3	
Total Current (mA)	29.5	25	21	

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

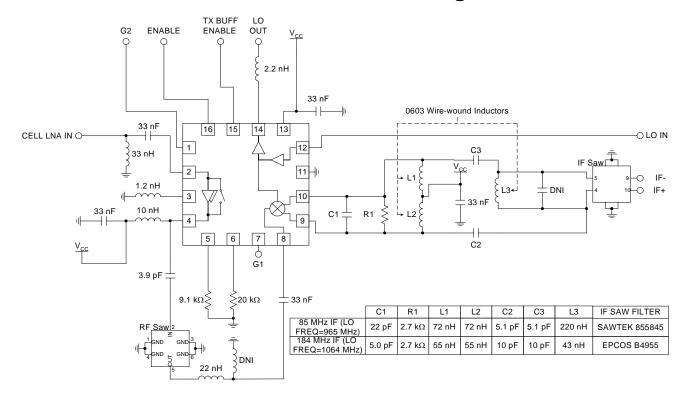
Pin	Function	Туре	Description	Interface Schematic
1	G2	DI	Gain control logic input. See logic control table.	intoriaco concinatio
-	-			G2 O
2	LNA IN	AI	Cellular LNA input.	LNA IN OLIVA OUT
3	LNA EMITTER	AO	Cellular LNA emitter. A small inductor connects this pin to ground. Cellular LNA gain can be adjusted by the inductance.	See pin 2.
4	LNA OUT	AO	Cellular LNA output. Simple external L-C components required for matching and VCC supply.	See pin 2.
5	ISET2	AO	An external resistor connected to this pin sets the current of the mixer. Increasing resistance decreases current.	
6	ISET1	AO	An external resistor connected to this pin sets the current of the LNA. Increasing resistance decreases current.	
7	G1	DI	Gain control logic input. See logic control table.	G1 O
8	MIX IN	AI	Cellular mixer RF single-end input.	MIX IN O
9	IF OUT+	AO	CDMA IF output. Open collector.	IF OUT-
10	IF OUT-	AO	CDMA IF output. Open collector.	See pin 9.
11	GND	Р	Ground.	
12	LO IN	Al	LO single-end input. Matched to $50\Omega$ .	LO IN Ο 70 Ω
13	VCC	Р	LO amplifier VCC external bypass capacitor may be required.	
14	LO OUT	AO	LO output. Internal DC block. Drives $50\Omega$	
15	TX BUFF ENABLE	DI	Logic input. High enables TX LO output buffer amplifiers.	TX BUFF ENABLE O
16	ENABLE	DI	Logic input. Low level powers down the IC.	ENABLE O
Pkg Base	GND	Р	Ground connection. The backside of the package should be soldered to a top side ground pad which is connected to the ground plane with multiple vias.	

Legend:

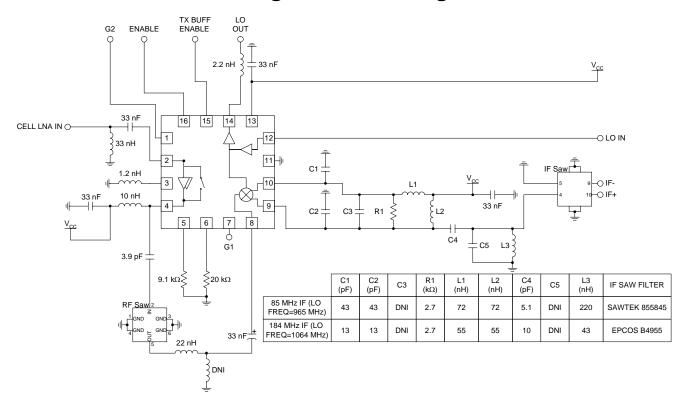
DI=Digital Input from Baseband Chip P=V<sub>CC</sub> or GND AI=Analog Input AO=Analog Output

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## **Application Schematic Differential IF Matching**

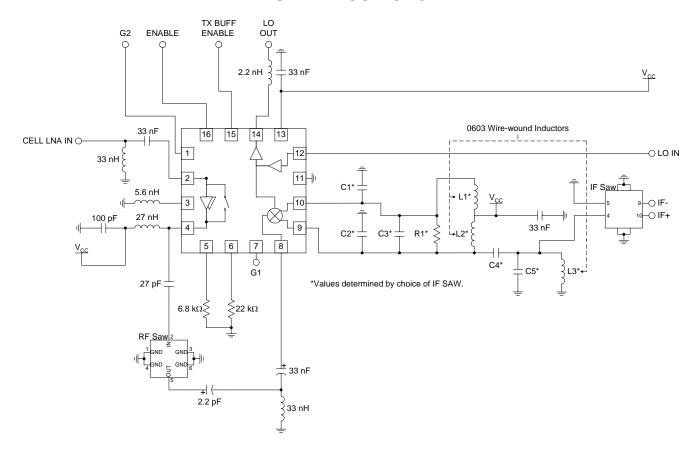


# **Application Schematic Single-End Matching**

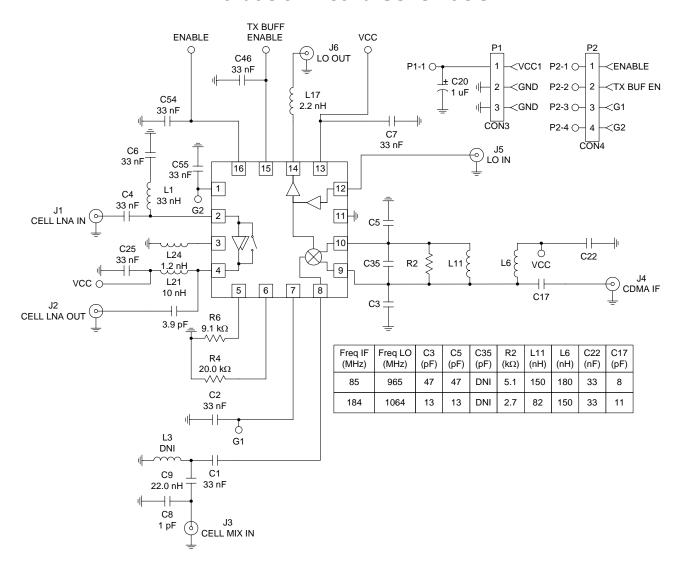


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### Application Schematic Single-End Matching CDMA450 Band

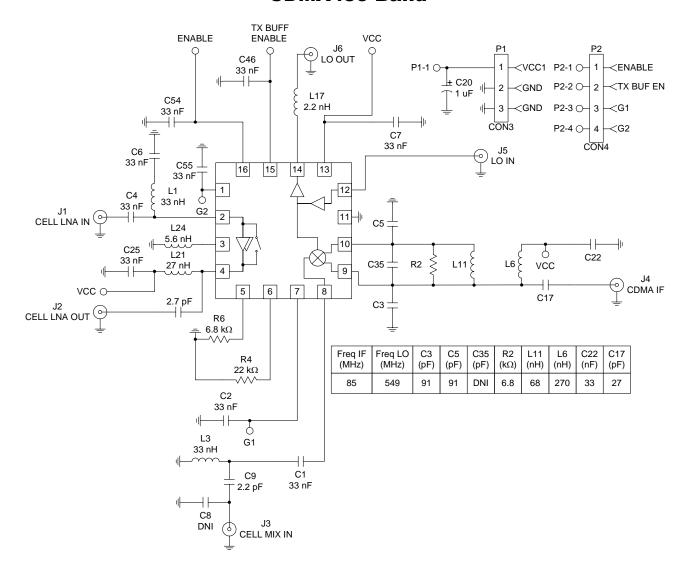


### **Evaluation Board Schematic**



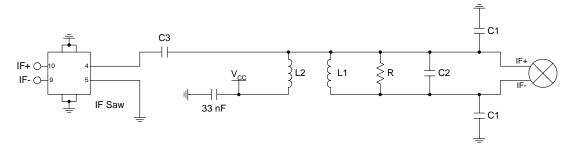
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## Evaluation Board Schematic CDMA450 Band



### **IF Output Interface Network**

### Single-End IF Matching



L1, C1, C2, and R form a current combiner which performs a differential to single-ended conversion at the IF frequency and sets the output impedance. In most cases, the resonance frequency is independent of R and can be set according to the following equation:

$$f_{IF} = \frac{1}{2\pi \sqrt{\frac{L1}{2}(C_1 + 2C_2 + C_{EQ})}}$$

Where  $C_{EQ}$  is the equivalent stray capacitance and capacitance looking into pins 9 and 10. An average value to use for  $C_{EQ}$  is 2.5pF.

R can then be used to set the output impedance according to the following equation:

$$R = \left(\frac{1}{4 \cdot R_{OUT}} - \frac{1}{R_P}\right)^{-1}$$

where R<sub>OUT</sub> is the desired output impedance and R<sub>P</sub> is the parasitic equivalent parallel resistance of L1.

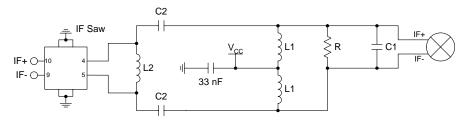
 $C_2$  should first be set to 0 and C1 should be chosen as high as possible (not greater than 39pF), while maintaining an  $R_P$  of L1 that allows for the desired  $R_{OUT}$ . If the self-resonant frequencies of the selected C1 produce unsatisfactory linearity performance, their values may be reduced and compensated for by including C2 capacitor with a value chosen to maintain the desired  $F_{IF}$  frequency.

L2 and C3 serve dual purposes. L2 serves as an output bias choke, and C3 serves as a series DC block.

In addition, L2 and C3 may be chosen to form an impedance matching network if the input impedance of the IF filter is not equal to R<sub>OUT</sub>. Otherwise, L2 is chosen to be large (suggested 120nH) and C3 is chosen to be large (suggested 22nF) if a DC path to ground is present in the IF filter, or omitted if the filter is DC-blocked.

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### **Differential IF Matching**



L1 and C1 are chosen to resonate at the desired IF frequency. C1 can be omitted and the value of L1 increased and utilized solely as a choke to provide  $V_{CC}$  to the open-collector outputs, but it is strongly recommended that at least some small-valued C1 (a few pF) be retained for better mixer linearity performance. R is normally selected to match the input impedance of the IF filter. However, mixer performance can be modified by selecting an R value that is different from the IF filter input impedance, and inserting a conjugate matching network between the Resistive Output Network and the IF filter.

C2 serve dual purposes. C2 serves as a series DC block when a DC path to ground is present in the IF filter. In addition, C2 may be chosen to improve the combine performance of the mixer and IF filter. L2 should choose to resonate with the internal capacitance of the SAW filter. Usually, SAW filter has some capacitance. Otherwise, L2 could be eliminated.

A practical approach to obtain the differential matching is to tune the mixer to the correct load point for gain, IIP3, and NF using the single-end current combiner method. Second, use the component values found in the single-end approach as starting point for the differential matching. The two-shunt capacitors in the single-end could be converted in a parallel capacitor and the parallel inductor in the single-end need to be converted in two-choke inductor. Third, set the DC block capacitors (C2) in the differential-end matching to a high value (i.e., 100pF) and retune the resonate circuit (C1 & L1) and the resistor (R) for optimal performance. After optimal performance is achieved and if performance is not satisfactory, decrease the series capacitors until optimal performance is achieved.

### **PCB Design Requirements**

#### **PCB Surface Finish**

The PCB surface finish used for RFMD's qualification process is electroless nickel, immersion gold. Typical thickness is 3µinch to 8µinch gold over 180µinch nickel.

#### **PCB Land Pattern Recommendation**

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

### **PCB Metal Land Pattern**

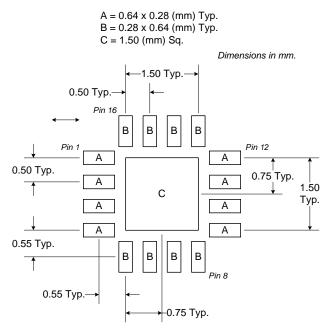


Figure 1. PCB Metal Land Pattern (Top View)

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